	Туре	L#	Hits	Search Text	DBs
1	BRS	L1	1890	257/723.ccls.	US- PGPU B; USPA T; USO CR
2	BRS	L2	1324	257/724.ccls.	US- PGPU B; USPA T; USO CR
3	BRS	L3	429	257/723.ccls.	EPO; JPO; DER WEN T; IBM_ TDB
4	BRS	L4 <u>.</u>	498	257/724.ccls.	EPO; JPO; DER WEN T; IBM_ TDB
5	BRS	L5	102	(substrate and (insulat\$3 or dielectric or protective) and (electrode or pad) and (wiring or conduct\$3) and metal and resistor and capacitor).clm.	US- PGPU B

	Туре	L#	Hits	Search Text	DBs
6	BRS	L6	110	(substrate and (insulat\$3 or dielectric or protective) and (electrode or pad) and (wiring or conduct\$3) and (metal or wire) and resistor and capacitor).clm.	US- PGPU B
7	BRS	L7	30	(substrate and (insulat\$3 or dielectric or protective) and (electrode or pad) and (wiring or conduct\$3) and (metal or wire) and resistor and capacitor and exposed).clm.	US- PGPU B